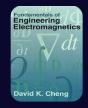
練習I

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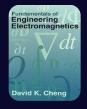
解答



2年前提供

The main difference between convection and conduction currents is that conduction currents are governed by Ohm's Law, and convection currents are not. Both are caused by the motion of free charges.





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解答



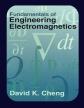
2年前提供

The relationship between convection current density $ec{J}$ and the velocity of the charge carriers $ec{u}$ is:

$$ec{J}=
ho_eec{u},$$

where ρ_e is free charge per unit volume.

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解答

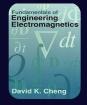


2年前提供

The mobility of the electron in a conductor μ_e , is a constant of proportionality between the average drift velocity and the electric field intensity:

$$ec{u_e} = -\mu_e ec{E}$$

It is measured in $m m^2/Vs$.



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解答



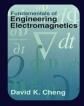
2年前提供

The point form of Ohm's Law is:

$$ec{J} = \sigma ec{E} ~~({
m A/m^2}),$$

where $ec{J}$ is current density, σ is conductivity, and $ec{E}$ is field intensity.

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解答



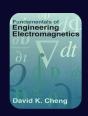
2年前提供

Conductivity σ is a macroscopic constitutive parameter of the medium, and it is reciprocal to resistivity. For semiconductors, it depends on the concentration and mobility of both electrons and holes:

$$\sigma = -
ho_e \mu_e +
ho_h \mu_h$$

The SI unit is
$$\frac{A}{V \cdot m}$$
 or $\frac{S}{m}$.





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解答



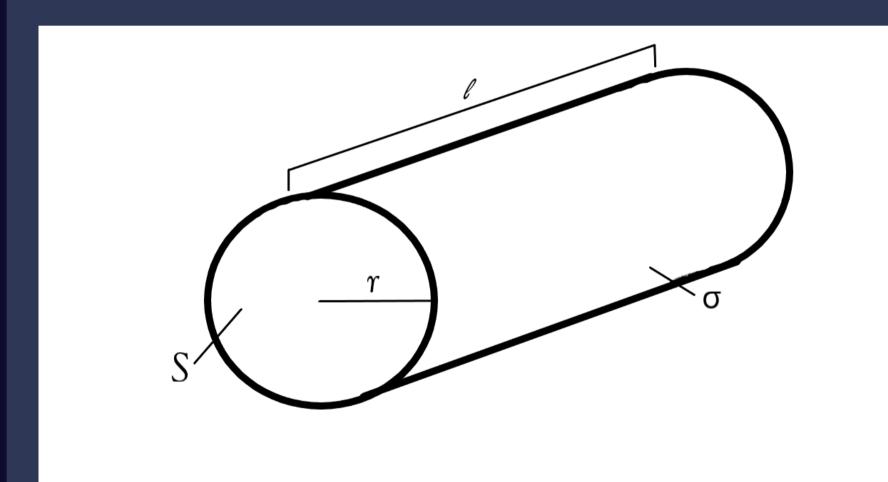
2年前提供

步驟I

步驟1/2

Resistance of a round wire is calculated using this formula:

$$R = rac{l}{\sigma S}$$



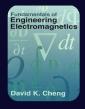
步驟2

步驟2/2

If the initial radius is r_1 , then the doubled radius is $r_2=2\cdot r_1$. Initial cross section of the wire is S_1 , and now it is $S_2=4\cdot S_1$, because $S=r^2\pi$. Now the resistance is:

$$R_2 = rac{l}{\sigma S_2} = rac{l}{\sigma \cdot 4S_1} = 0.25 rac{l}{\sigma S_1}$$

So, if the radius doubles, the resistance decreases 4 times.



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解答



2年前提供

The equation of continuity looks like this:

$$\Delta \cdot ec{J} = -rac{\partial
ho_v}{\partial t},$$

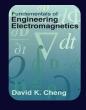
and, for steady currents it is reduced to this:

$$\Delta\cdotec{J}=0$$

This means that steady currents are divergenceless, and the field lines close upon themselves.

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解答



2年前提供

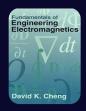
Kirchhoff's current law states that the algebraic sum of all the currents flowing out of a junction in an electric circuit is zero. It can be written as:

$$\sum_{j}I_{j}=0$$

練習9

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解答



2年前提供

步驟1

步驟1/2

Relaxation time τ is a time constant, and it equals to:

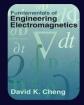
$$au = rac{\epsilon}{\sigma} \quad ext{(s)}$$

It is used for calculating how the volume density of the charge decays exponentially over time.

步驟2

步驟2/2

For copper, relaxation time is $au=1.53 imes10^{-19}~ ext{s}$, so the order of magnitude is -19.



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解答



2年前提供

Joule's law states that for a volume V, the total electric power converted into heat is:

$$P = \int_V ec{E} \cdot ec{J} \, dv$$

Using Ohm's Law $(ec{J}=\sigmaec{E})$, it can be written like this:

$$egin{aligned} P &= \int_V ec{E} \cdot ec{J} \, dv = \int_V ec{E} \cdot \sigma ec{E} \, dv = \int_V E \cdot \sigma \, dv \ P &= \int_V ec{E} \cdot ec{J} \, dv = \int_V ec{\sigma} \cdot ec{J} \, dv = \int_V \dfrac{J}{\sigma} \cdot dv \end{aligned}$$

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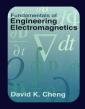
解答



2年前提供

The boundary conditions of steady current at the interface of two media with different conductivities σ_1 and σ_2 are:

- ullet normal components: $J_{1n}=\overline{J_{2n}}$
- ullet tangential components: $\dfrac{J_{1t}}{J_{2t}}=\dfrac{\sigma_1}{\sigma_2}$



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解答



2年前提供

Relationship between conductance G and capacitance C can be described with this formula:

$$rac{C}{G} = rac{\epsilon}{\sigma}$$

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解答



2年前提供

Relationship between resistance R and capacitance C can be described with this formula:

$$RC = rac{\epsilon_0 \epsilon_r}{\sigma}$$